STUSB02E



USB Transceiver

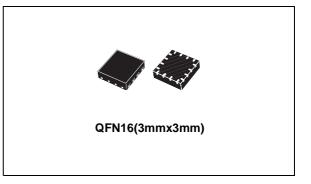
Features

- Compliant to USB v2.0 for Full-speed (12Mb/s) and Low-speed (1.5Mbps) Operation
- ±14KV on D+, D- Lines; ±5KV on VBUS
- ESD Compliant To IEC-61000-4.2 (Level 3)
- Separate I/o Supply With Operation Down To 1.6V
- Integrated Speed Select Termination Supply
- Very Low Power Consumption To Meet USB 'suspend' Current Requirements
- Small QFN16 Lead Free Package
- No Power Supply Sequencing Requirements
- Software Controlled Re-enumeration

Description

The STUSB02E is a single chip transceiver that complies with the physical layer specifications of the Universal Serial Bus (USB) v2.0 standard. It has an integrated 5V to 3.3V regulator which allows direct powering from the VBUS. The

Order Codes



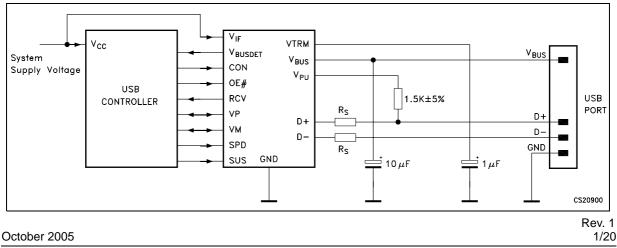
transceiver has an integrated voltage detector to detect the presence of the VBUS voltage.

The transceiver also supports Sharing mode when VBUS is not present, which allows the D+/ D– lines to be shared with other serial protocols.

It supports both full-speed (12Mbps) and lowspeed (1.5Mbps) operation. It is also designed to operate down to 1.6V so that it is compatible with lower system voltages of most portable systems, which include PDAs, MP3 Player and Cell phones to mention few.

Туре	Package	Comments
STUSB02EQR	QFN16 (3mm x 3mm)	3000 parts per reel

Typical Application

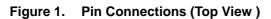


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1 Pin Configuration



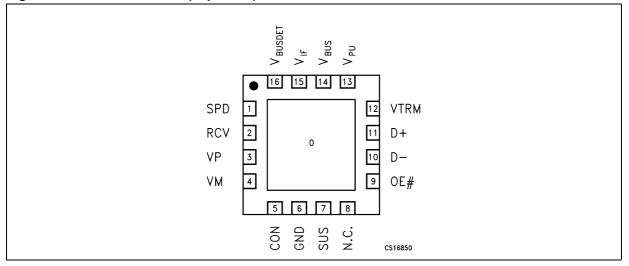


Table 1. Pin Description

PIN N°	SYMBOL	I/O	NAME AND FUNCTION
0	N.C.		Not Connected.
15	V _{IF}	Ι	System Interface Supply Voltage (1.6V to 3.6V). (return) Provides reference supply voltage for system I/O interface signals.
1	SPD	Ι	Edge Rate Control. A logic HIGH operates at edge rates for "fullspeed" operation. A logic LOW operates edge rates for "lowspeed" operation.
2	RCV	0	Receive Data. Output for USB differential data. (see Table 2)
3	VP	I/O	If OE# = H, VP = Receiver output (+) If OE# = L, VP = Driver input (+) (see <i>Table 2</i>)
4	VM	I/O	If OE# = H, VM = Receiver output (-) If OE# = L, VM = Driver input (-) (see <i>Table 2</i>)
5	CON	Ι	CONNECT (input). Controls state of V _{PU} . Refer to V _{PU} pin description for detail.
6	GND		Ground Reference
7	SUS		Suspend (active-high). Turns off internal circuits to reduce supply current.
9	OE#	Ι	Output Enable (active-low). Enables transceiver data transmission onto the bus. When not active, the transceiver is in the receive mode. (see <i>Table 2</i>)
10, 11	D-, D+	I/O	Differential data lines that conform to the USB v2.0 standard. (see Table 2)
12	VTRM	0	3.3V Reference Supply Output. Requires a 1.0µF decoupling capacitor for stability.
13	V _{PU}	0	Pull-up Supply Voltage Output. Used to connect 1.5K pull-up speed detect resistor. If CON = 0, V_{PU} is high impedance. If CON = 1, V_{PU} = 3.3V ±10%.
14	V _{BUS}	Ι	USB Bus Supply Voltage (4V to 5.5V). Supplies power to the USB transceiver and internal circuitry.
8	N.C.		Not connected.
16	V _{BUSDET}	0	V_{BUS} indicator output. When V_{BUS} > 2.9V, V_{BUSDET} = High and when < 2.2V, V_{BUDET} = Low.



2 Functional Tables

Table 2. Function Selection

SUS	OE#	D+, D-	RCV	VP/VM	FUNCTION
L	L	Driving	Active	Active	Normal transmit mode
L	Н	Receiving	Active	Active	Normal receive mode
Н	L	Hi-Z	L	Not Active	Low power state
Н	Н	Hi-Z	L	Active	Receiving during suspend (low power state) ⁽¹⁾

(1) During suspend VP and VM are active in order to detect out of band signalling conditions

Table 3. Truth Table During Normal Mode

0E# = L					
INF	PUT	OUTPUT			DEOUNT
VP	VM	D+	D-	RCV	RESULT
L	L	L	L	Х	SE0
L	Н	L	Н	L	Logic Low
Н	L	Н	L	Н	Logic High
Н	Н	Х	Х	Х	Undefined
DE# = H					-
INF	PUT		OUTPUT		DECULT
D+	D-	VP	VM	RCV	RESULT
L	L	L	L	Х	SE0
L	Н	L	Н	L	Logic Low
Н	L	Н	L	Н	Logic High
Н	Н	Х	Х	Х	Undefined

X = Undefined



3 Maximum Ratings

Table 4. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V _{BUS}	Supply Voltage	6	V
V+	All other Inputs	-0.5 to 4.6	V
Ι _Ο	Output Current (D+, D-)	± 50	mA
Ι _Ο	Output Current (all others)	± 15	mA
lı	Input Current	± 50	mA
	D+, D-, HBM (Note 3)	± 14	
ESD	V _{BUS} (Note 3)	± 5	KV
	All other pins (Note 3)	±2	
T _{STG}	Storage Temperature Range	-65 to + 150	°C
T _{OPR}	Operating Temperature Range	-40 to + 85	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional Operation under these conditions is not implied.

Note 3. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF.

Table 5.Thermal Data

Symbol	Parameter	Value	Unit
R _{thJA}	Thermal Resistance Junction-Ambient	59	°C/W



4 Electrical Characteristics

Table 6. DC Electrical Characteristics (System and USB Interface)

(V_{IF} = 3.6V, V_{BUS} = 5V unless otherwise noted; T_A = 25°C, specifications over temperature, -40 to 85°C)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	
V _{BUS}	USB Supply Voltage		4		5.5	V	
V _{IF}	System I/F Supply Voltage		1.6		3.6	V	
V _{IL}	Low Level Input Voltage (Note 4)				0.15V _{IF}	V	
V _{IH}	High Level Input Voltage (Note 4)		0.85V _{IF}			V	
V _{OL}	Low Level Output Voltage (Note 4)	I _{OL} = 20μΑ	0		100	mV	
V _{OH}	High Level Output Voltage (Note 4)	Ι _{ΟΗ} = -20μΑ	VIF-100		V_{IF}	mV	
۱ _{IL}	Input Leakage Current (Note 4)		-5		5	μA	
		D+, D- are idle, $OE# = SUS = 0$			5		
		D+, D- are idle, OE# = SUS = 1			5		
I _{IF}	V _{IF} Supply Current (Note 7)	D+, D- active, C _{LOAD} = 50pF,			650		
יו⊢		SPD = 1, f = 6MHz, (Note 5)			050	μA	
		D+, D- active, $C_{LOAD} = 600 pF$,			75		
		SPD = 0, f = 750KHz, (Note 5)			10		
		D+, D- are idle, $V_{BUS} = 5.25V$			200		
		Suspend Mode (SUS = 1), OE# = 1, SPD = 1				μA	
		D+, D- are idle, V _{BUS} = 5.25V			~	mA	
		SPD = 1, OE# = SUS = 0			5		
		D+, D- are idle, V _{BUS} = 5.25V			700		
		OE# = SUS = SPD = 0			700		
I _{BUS}	V _{BUS} Supply Current	D+, D- are idle, V _{BUS} = 5.25V			350	μA	
		OE# = 1, SUS = SPD = 0			350		
		D+, D- active, V _{BUS} = 5.25V					
		$C_{LOAD} = 50$ pF, SPD = 1, f = 6 MHz			10		
		OE# = SUS = 0 (Note 5)				س ۸	
		D+, D- active, V _{BUS} = 5.25V				mA	
		C _{LOAD} = 600pF, f = 750 KHz,			5		
		OE# = SUS = SPD = 0 (Note 5)					
IVPULEAK	V _{PU} Leakage Current	CON = 0, V _{PU} = 0V	-5		5	μA	
I _{VIFLEAK}	V _{IF} Leakage Current	$V_{IF} = 3.6V, V_{BUS} = 0V$	-5		5	μA	
V _{PU}	Pull-Up Output Voltage	$I_{\text{TERM}} = 200 \mu \text{A}, V_{\text{BUS}} = 4 \text{ to } 5.25 \text{V}$	3		3.6	V	
R _{SW}	V _{PU} Internal Switch Resistance	$I_{\text{TERM}} = 10$ mA, $V_{\text{BUS}} = 4$ to 5.25V	7	9	11	W	

Note 1. Exceeding the absolute maximum rating may damage the device.

Note 2. The device is not guaranteed to function outside its operating rating.

Note 3. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF.

Note 4. Specification applies to the following pins: SUS, SPD, RCV, CON, VP, VM, OE#, VBUSDET.

Note 5. Characterized specification(s), but not production tested.

Note 6. All AC parameters guaranteed by design but not production tested.

Note 7. RCV = NO LOADED



Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{BUS}	USB Supply Voltage		4		5.5	V
V _{IF}	System I/F Supply Voltage		1.6		3.6	V
VIL	Low Level Input Voltage (Note 4)				0.15V _{IF}	V
V_{IH}	High Level Input Voltage (Note 4)		0.85V _{IF}			V
V _{OL}	Low Level Output Voltage (Note 4)	I _{OL} = 20μΑ			0.1	V
V _{OH}	High Level Output Voltage (Note 4)	I _{OH} = 20μA	$0.9 V_{IF}$			V
۱ _{IL}	Input Leakage Current (Note 4)		-5		5	μA
		D+, D- are idle, $OE# = SUS = 0$			5	
I _{IF}	V _{IF} Supply Current (Note 7)	D+, D- active, C _{LOAD} = 50pF, SPD = 1, f = 6MHz, (Note 5)		450		μA
		D+, D- active, $C_{LOAD} = 50pF$, SPD = 0, f = 750KHz, (Note 5)		50		·
		D+, D- are idle, $V_{BUS} = 5.25V$ Suspend Mode (SUS = 1)		70	150	μA
		D+, D- are idle, $V_{BUS} = 5.25V$ SPD = 1, OE# = SUS = 0		3.0		mA
		D+, D- are idle, $V_{BUS} = 5.25V$ OE# = SUS = SPD = 0		300		
I _{BUS}	V _{BUS} Supply Current	D+, D- are idle, V _{BUS} = 5.25V OE# = 1, SUS = SPD = 0		150		μA
		D+, D- active, $V_{BUS} = 5.25V$ $C_{LOAD} = 50pF$, SPD = 1, f = 6 MHz OE# = SUS = 0 (Note 5)		7.3		mA
		D+, D- active, $V_{BUS} = 5.25V$ $C_{LOAD} = 600$ pF, f = 750 KHz, OE# = SUS = SPD = 0 (Note 5)		3.6		
IVPULEAK	V _{PU} Leakage Current	CON = 1, V _{PU} = 0V	-5		5	μA
I _{VIFLEAK}	V _{IF} Leakage Current	$V_{IF} = 3.6V, V_{BUS} = 0V$	-5		5	μA
V _{PU}	Pull-Up Output Voltage	$I_{\text{TERM}} = 200 \mu \text{A}, V_{\text{BUS}} = 4 \text{ to } 5.25 \text{V}$		3.3		V
R _{SW}	V _{PU} Internal Switch Resistance	$I_{\text{TERM}} = 10 \text{mA}, V_{\text{BUS}} = 4 \text{ to } 5.25 \text{V}$		9		W

Table 7. DC Electrical Characteristics (System and USB Interface)

(V_{IF} = 3.6V, V_{BUS} = 5V unless otherwise noted; $T_A = 25^{\circ}C$)

Note 1. Exceeding the absolute maximum rating may damage the device. Note 2. The device is not guaranteed to function outside its operating rating. Note 3. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF. Note 4. Specification applies to the following pins: SUS, SPD, RCV, CON, VP, VM, OE#, VBUSDET. Note 5. Characterized specification(s), but not production tested. Note 6. All AC parameters guaranteed by design but not production tested. Note 7. RCV = NO LOADED



Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
		Air Discharge (10 pulses)		± 8		
ESD		Contact Discharge (10 pulses)		±6		кv
-	IEC-1000-4-2 (V _{BUS} only)	Air Discharge (10 pulses)		±5		ΓV
	12C-1000-4-2 (V _{BUS} 0119)	Contact Discharge (10 pulses)		±5		

Table 9.

DC Electrical Characteristics (Transceiver) (V_{IF} = 3.6V, V_{BUS} = 5V unless otherwise noted; $T_A = 25$ °C, specifications over temperature, -40 to 85°C)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{LO}	Hi-Z State Data Line Leakage (Suspend Mode)	V _I = 0 to 3.3 V, SUS = 1	-10		10	μA
V _{DI}	Differential Input Sensitivity	(D+) - (D-)	0.2			V
V _{CM}	Differential Common Mode Range	Includes V _{DI} range	0.8		2.5	V
V _{SE}	Single Ended Receiver Threshold		0.8		2.0	V
V _{RHYS}	Receiver Hysteresis	V _{CM} = 0.8 V		100		mV
V _{OL}	Static Output Low	$R_L = 1.5 \text{ K}\Omega \text{ at } 3.6 \text{V} \text{ (see test circuit)}$			0.3	V
V _{OH}	Static Output High	$R_L = 15 K\Omega$ at GND (see test circuit)	2.8		3.6	V
CI	Transceiver Capacitance	Pin to GND		25		pF
Z _{DRV}	Driver Output Resistance	Steady state drive	9		22	W

Table 10. DC Electrical Characteristics (Transceiver) $(V_{IF} = 3.6V, V_{BUS} = 5V$ unless otherwise noted; $T_A = 25^{\circ}C$)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{LO}	Hi-Z State Data Line Leakage (Suspend Mode)	V _I = 0 to 3.3 V, SUS = 1	-2		2	μA
V _{DI}	Differential Input Sensitivity	(D+) - (D-)	0.2			V
V _{CM}	Differential Common Mode Range	Includes V _{DI} range	0.8		2.5	V
V_{SE}	Single Ended Receiver Threshold		0.8		2	V
V _{RHYS}	Receiver Hysteresis	V _{CM} = 0.8 V		50		mV
V _{OL}	Static Output Low	$R_L = 1.5 \text{ K}\Omega \text{ at } 3.6\text{V}$ (see <i>Test Circuits</i>)			0.3	V
V _{OH}	Static Output High	R _L = 15 KΩ at GND (see <i>Test Circuits</i>)	2.8		3.6	V
CI	Transceiver Capacitance (3)	Pin to GND		25		pF
Z _{DRV}	Driver Output Resistance	Steady state drive		16		W

(3) Pins D+, D-

STUSB02E

Table 11. AC Electrical Characteristics

$(V_{IF} = 3.6V, V_{BUS} = 5V \text{ unless otherwise noted}; T_A = 25^{\circ}C.)$ (Note 6)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	
Τ _R		C _L = 50pF (<i>Figure 3</i>)	75				
	Transition Rise Time (LOW SPEED)	$C_{L} = 600 pF$			300	ns	
Τ _F	Transition Fall Time (LOW SPEED)	C _L = 50pF (<i>Figure 3</i>)	75			ns	
		$C_L = 600 pF$			300		
$T_{R_{I}}T_{F}$	Rise/Fall Time Matching (LOW SPEED)	(T _R , T _F)	80		125	%	
V _{CRS}	Output Signal Crossover Voltage (LOW SPEED)		1.3		2	V	
Τ _R	Transition Rise Time (FULL SPEED)	C _L = 50pF (<i>Figure 3</i>)	4		20	ns	
Τ _F	Transition Fall Time (FULL SPEED)	C _L = 50pF (<i>Figure 3</i>)	4		20	ns	
$T_{R_{I}}T_{F}$	Rise/Fall Time Matching (FULL SPEED)	(T _R , T _F)	90		111.11	%	
V _{CRS}	Output Signal Crossover Voltage (FULL SPEED)		1.3		2	V	
t _{PVZ}	OE# TO RCVR Tri-State Delay	Figure 2		3		ns	
toro	Receiver Tri-State to Transmit Delay	LOW SPEED (<i>Figure 2</i>)	13			ns	
t _{PZD}	Receiver III-State to Hansmit Delay	FULL SPEED (<i>Figure 2</i>)	32				
t _{PDZ}	OE# TO RCVR Tri-State Delay	Figure 2		6		ns	
t _{PZV}	Driver Tri-State to Receive Delay	Figure 2		27		ns	
t _{PLH} t _{PHL}	VP, VM to D+, D- Propagation Delay	Figure 5		16	20	ns	
t _{PLH} t _{PHL}	D+, D- to RCV Propagation Delay	Figure 4		13	20	ns	
t _{PLH} t _{PHL}	D+, D- to VP, VM Propagation Delay	Figure 4		8	20	ns	

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Note 2. The device is not guaranteed to function outside its operating rating.

Note 3. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF.

Note 4. Specification applies to the following pins: SUS, SPD, RCV, CON, RCV, VP, VM, OE#.

Note 5. Characterized specification(s), but not production tested.

Note 6. All AC parameters guaranteed by design but not production tested.

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5 Timing Diagram



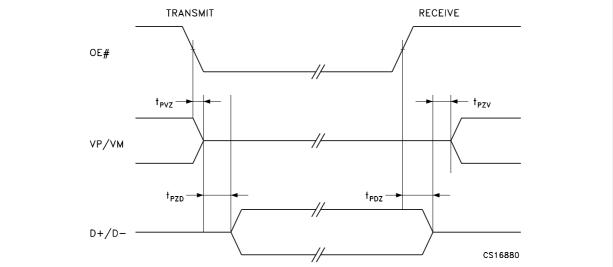
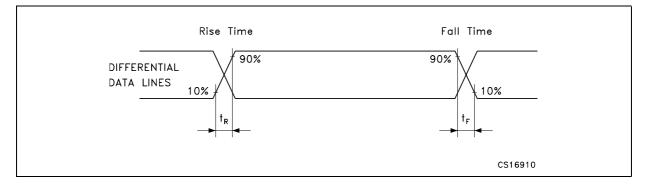


Figure 3. Rise and Fall Times







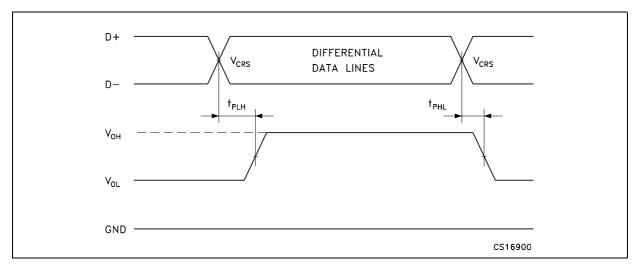
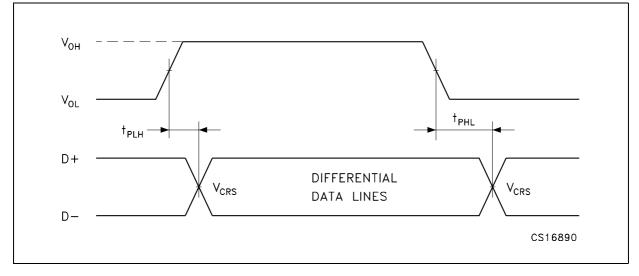


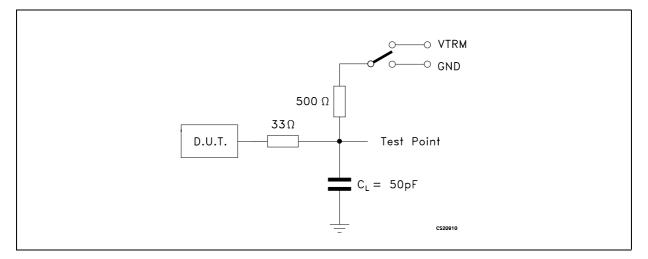
Figure 5. Driver Propagation Delay (C_L = 50pF)



Minimum Timing LS and maximum timing FS



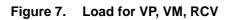
Figure 6. Enable and Disable Time Circuit



Switch = GND for t_{PZH} and $t_{\text{PHZ}};$ V = VTRM for t_{PZL} and t_{PLZ}



6 Test Circuits



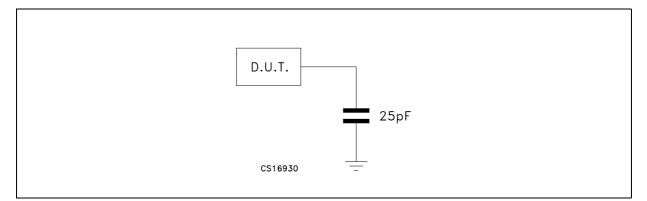


Figure 8. Load for D+, D-

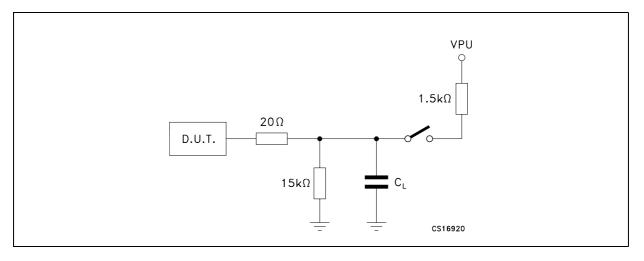
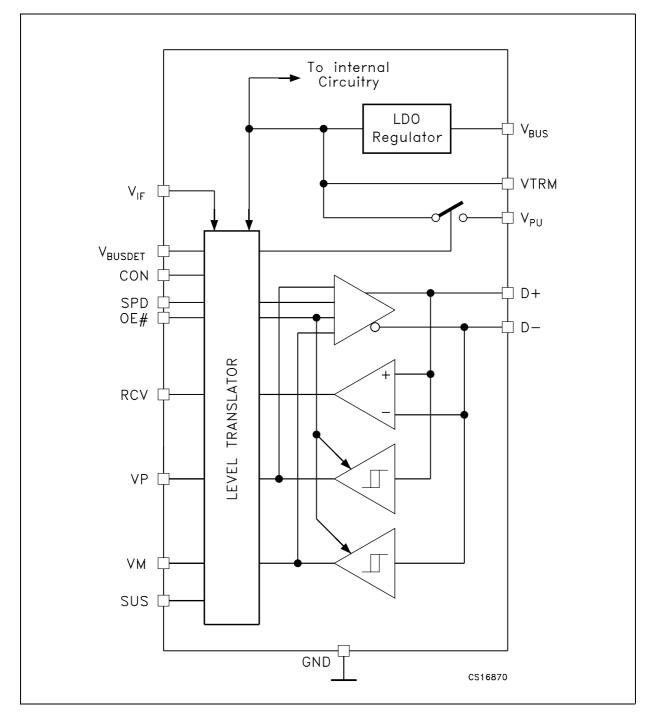




Figure 9. Functional Diagram





7 Functional Description

The STUSB02E is designed to provide USB connectivity in portable systems where available system supply voltages are not able to satisfy USB requirements. The STUSB02E can operate down to supply voltages of 1.6V and still meet USB physical layer specifications. As shown in the circuit above, the STUSB02E takes advantage of the USB supply voltage, V_{BUS} , to operate the transceiver. The system voltage, V_{IF} , is used to set the reference voltage used by the digital I/O lines interfacing to the system controller. Internal circuitry provides translation between the USB and system voltage domains. V_{IF} will typically be the main supply voltage rail for the controller.

In addition, a 3.3V, 10% termination supply voltage, V_{PU} , is provided to support speed selection. V_{PU} can be disabled or enabled under software control via the CON input. This allows for software-controlled connect or disconnect states. A 1.5K resistor is required to be connected between this pin and the D+ or D– lines to respectively specify full speed or low speed operation.

The use of ESD transient protection devices is not required for operation, but is recommended.

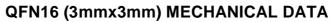


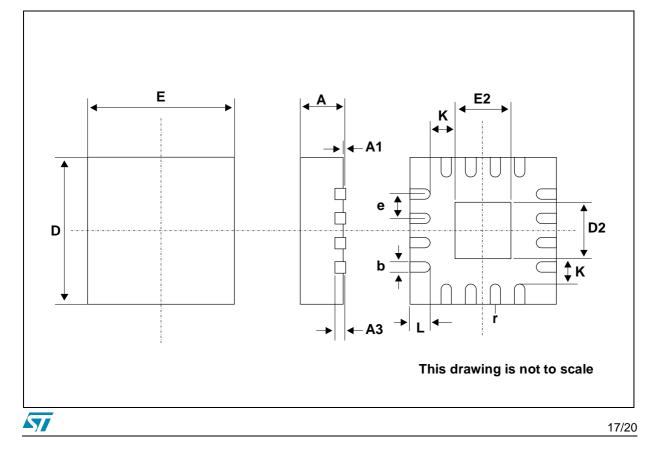
8 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



DIM.	mm.			inch			
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А	0.80	0.90	1.00	0.032	0.035	0.039	
A1		0.02	0.05		0.001	0.002	
A3		0.20			0.008		
b	0.18	0.25	0.30	0.007	0.010	0.012	
D		3.00			0.118		
D2	1.55	1.70	1.80	0.061	0.067	0.071	
E		3.00			0.118		
E2	1.55	1.70	1.80	0.061	0.067	0.071	
е		0.50			0.020		
K		0.20			0.008		
L	0.30	0.40	0.50	0.012	0.016	0.020	
r	0.09			0.006			





0.519

0.724

57

0.130

0.130

0.043

0.157

С

D

Ν

Т

Ao

Во

Ko Po 12.8

20.2

60

			()				
DIM.	mm.			inch			
Diwi.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	

13.2

18.4

3.3

3.3

1.1

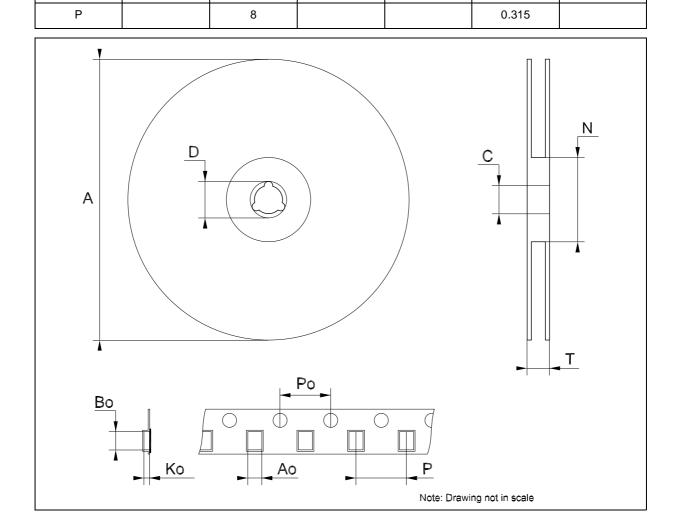
4

0.504

0.795

2.362

Tape & Reel QFNxx/DFNxx (3x3) MECHANICAL DATA



9 Revision History

Date	Revision	Description of Change
19-Oct-2005	1	First Release.



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